Signals in the Well Electron Multiplier with the DLC anode (part II)

<u>A.Kashchuk ^a</u> (anatoli.kachtchouk@cern.ch), V. Akulich ^b, K.Afanaciev ^c, V.Bayev ^c, N.Kravchuk ^d, N.Kuchinskiy ^d, O.Levitskaya ^a,







s=500 μm, d=200 μm, r~15 μm Thickness 500 µm (FR4)

Dielectric substrate with Copper on one side

- 2 1-st electrode (cathode)
- 3 Well-like hole
- 4 DLC layer (anode)
- 5 Dielectric substrate with Copper on both sides
- 6 2-nd electrode (Copper mesh)
- 7 3-rd electrode (strip/pixel readout)

S.Movchan^d, A.V.Solin^c, A.A.Solin^c, V.Tchekhovski^c

^a PNPI, Gatchina; ^b PhTI, Minsk; ^c INP BSU, Minsk; ^d JINR, Dubna





Detector schemas under tests



Equivalent diagrams for DLC layer as RC-system

5 0.4



2-nd electrode (3-rd electrode similar). Capacitors normalized to RC-cell (per one hole)



• At f=0 (d.c.) DLC layer is R. At low frequencies $f \ll 1/\pi\tau$ DLC layer is R/2 and



Reconstruction of the signal in the input done using convolution y(t)=x(t) * h(t), where x(t) - input,



- h(t) amp. impulse response (*red*), y(t) output (*blue*), Y(t) reconstruction (*green*). • Assuming that x(t) is composed of $\delta(t)$ (width 1 ns) and step-function (amplitude 1%) and assuming that T is the end of the input signal we obtain an agreement Y(t) and y(t) within ~10% (*green*), *a*).
- The rise time of Y(t) becomes too large (green), if the $\delta(t)$ is missing on the input, b).

 $2C_i$ connected in series, where R is the surface resistivity, C_i - local capacitance to electrode i. At high frequencies DLC layer is C_i , where i=1the 1-st, i=2 – the 2-nd and i=3 – the 3-rd electrode. $\tau = RC_i$.

Five characteristic time intervals

• Below we show 5 characteristic time intervals which define the rate capability of the detector:



- rise time 10 ns (b). • Difference 3 ns gives the input pulse width. • A relative influence of the R and size of the mesh to the "bump" induced by electrons moving along
- Useful formulas one can find in ref. [3].



Avalanche electrons reach DLC induce the main signal (~30 ns in our case for Fe-55 with fast amplifier Tp=5 ns, the real signal is 10-times shorter); II. Electrons move along the DLC layer adding some tail ("bump") to the signal induced by ions - about 200 ns in our case; III. Ions drift along the hole at $E \sim 50 \text{ kV/cm}$ and induce characteristic ion tail in the signal; IV. Ions leave the hole (E reduced from 50 to 1 kV/cm); V. Ions drift to the cathode at $E \sim 1 \text{ kV/cm}$.

Conclusion

- The Well (micro-Well *depending on thickness*) detector [1] is a new class of MPGD without induction gap in contrast to GEM [2].
- In many features and characteristics outperforms the GEM/THGEM.
- The Well detector with the DLC anode of thickness ~100 nm with the signal pulse width, as shown in this work, is able to withstand high particles fluxes up to 30 MHz/cm².

References

- R.Bellazzini, et al. The WELL detector. NIM A423 (1999), 125-134.
- 2. F.Sauli. GEM: a new concept for electron amplification in gas detectors, NIM A-386 (1997), 531-534.
- 3. W. Riegler. Electric fields, weighting fields, signals and charge diffusion in detectors including resistive material. 2016 JINST 11 P11002.

the help in measurements the Raman spectra, Yi Zhou (University of Sci. and Technology of China) who kindly presented his DLC in order to we could compare it with our DLC presented in this work. A.Kashchuk and O.Levitskaya acknowledge the financial support of Russian Ministry of Science, agreement №075-15-2019-954 by 31.05.2019, unique identification number of project RFMEFI60718X0200.